2SJ277



Ultrahigh-Speed Switching Applications

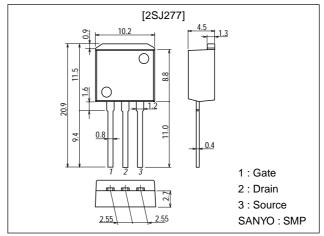
Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.
- · Surface mount type device making the following possible.
 - · Reduction in the number of manufacturing processes for 2SJ277-applied equipment.
- · High density surface mount applications.
- · Small size of 2SJ277-applied equipment.

Package Dimensions

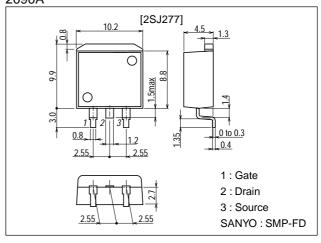
unit:mm

2093A



unit:mm

2090A



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- SANYO assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges,or other parameters) listed in products specifications of any and all SANYO products described or contained herein.

Specifications

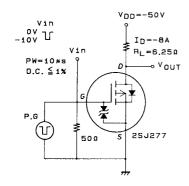
Absolute Maximum Ratings at Ta = 25°C

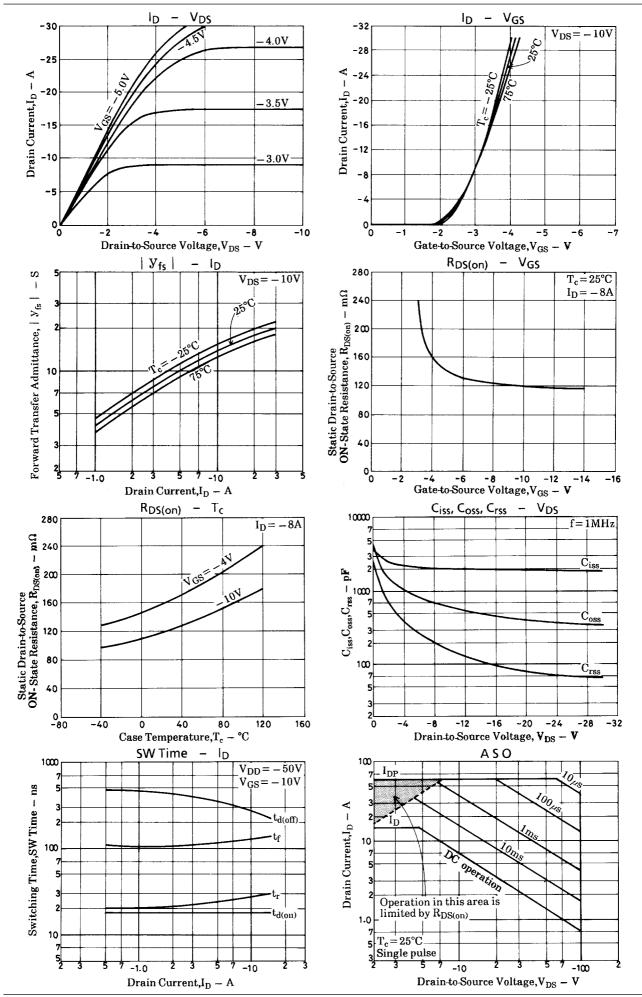
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-100	V
Gate-to-Source Voltage	V _{GSS}		±15	V
Drain Current (DC)	ID		-15	Α
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-60	Α
Allowable Power Dissipation	D_		1.65	W
	P _D	Tc=25°C	70	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

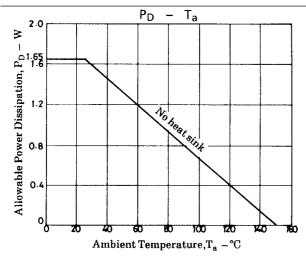
Electrical Characteristics at Ta = 25°C

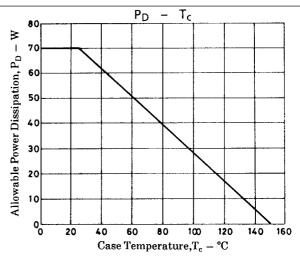
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _{GS} =0	-100			V
Gate-to-Source Breakdown Voltage	V(BR)GSS	I _G =±100μA, V _{DS} =0	±15			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-100V, V _{GS} =0			-100	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±12V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-1mA	-1.0		-2.0	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-8A	7.5	13		S
Static Drain-to-Source ON-State Resistance	R _{DS(on)}	I _D =-8A, V _{GS} =-10V		120	160	mΩ
	R _{DS(on)}	I _D =-8A, V _{GS} =-4V		160	220	mΩ
Input Capacitance	Ciss	V _{DS} =-20V, f=1MHz		1900		pF
Output Capacitance	Coss	V _{DS} =-20V, f=1MHz		400		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-20V, f=1MHz		80		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		18		ns
Rise Time	t _r	See specified Test Circuit		25		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		300		ns
Fall Time	t _f	See specified Test Circuit		120		ns
Diode Forward Voltage	V _{SD}	I _S =-15A, V _{GS} =0		-1.0	-1.5	V

Switching Time Test Circuit









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